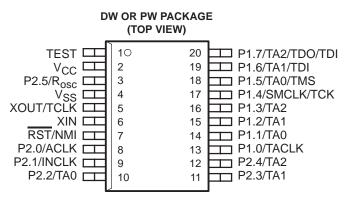
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- Low Supply Voltage Range 1.8 V to 3.6 V
- Ultralow-Power Consumption:
- Active Mode: 200 μA at 1 MHz, 2.2 V
 Standby Mode: 0.8 μA
 - Off Mode (RAM Retention): 0.1 μA
- Wake-Up From Standby Mode in less than 6 μs
- 16-Bit RISC Architecture, 125 ns Instruction Cycle Time
- Basic Clock Module Configurations:
 - Various Internal Resistors
 - Single External Resistor
 - 32 kHz Crystal
 - High Frequency Crystal
 - Resonator
 - External Clock Source
- 16-Bit Timer_A With Three Capture/Compare Registers
- Serial Onboard Programming, No External Programming Voltage Needed

- Family Members Include: MSP430F110: 1KB + 128B Flash Memory 128B RAM
 MSP430F112: 4KB + 256B Flash Memory 256B RAM
- Available in a 20-Pin Plastic Small-Outline Wide Body (SOWB) Package and 20-Pin Plastic Thin Shrink Small-Outline Package (TSSOP)
- For Complete Module Descriptions, Refer to the MSP430x1xx Family User's Guide, Literature Number SLAU049



description

The Texas Instruments MSP430 family of ultralow power microcontrollers consist of several devices featuring different sets of peripherals targeted for various applications. The architecture, combined with five low power modes is optimized to achieve extended battery life in portable measurement applications. The device features a powerful 16-bit RISC CPU, 16-bit registers, and constant generators that attribute to maximum code efficiency. The digitally controlled oscillator (DCO) allows wake-up from low-power modes to active mode in less than 6µs.

The MSP430F11x series is an ultralow-power mixed signal microcontroller with a built in 16-bit timer and fourteen I/O pins.

Typical applications include sensor systems that capture analog signals, convert them to digital values, and then process the data and display them or transmit them to a host system. Stand alone RF sensor front-end is another area of application.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

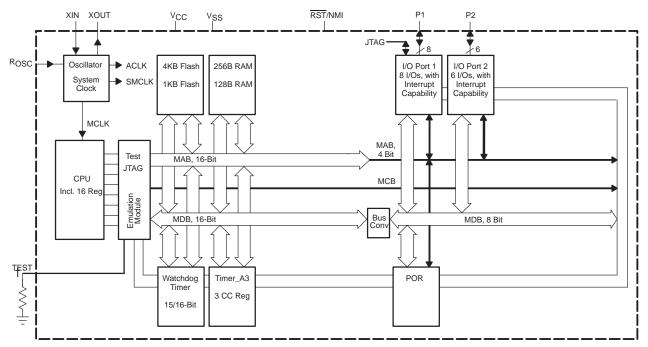


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AVAILABLE OPTIONS					
	PACKAGED DEVICES				
TA	PLASTIC 20-PIN SOWB (DW)	PLASTIC 20-PIN TSSOP (PW)			
-40°C to 85°C	MSP430F110IDW MSP430F112IDW	MSP430F110IPW MSP430F112IPW			

functional block diagram



 † A pulldown resistor of 30 k Ω is needed on F11x devices.



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Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
P1.0/TACLK	13	I/O	General-purpose digital I/O pin/Timer_A, clock signal TACLK input
P1.1/TA0	14	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI0A input, compare: Out0 output/BSL transmit
P1.2/TA1	15	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI1A input, compare: Out1 output
P1.3/TA2	16	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI2A input, compare: Out2 output
P1.4/SMCLK/TCK	17	I/O	General-purpose digital I/O pin/SMCLK signal output/test clock, input terminal for device programming and test
P1.5/TA0/TMS	18	I/O	General-purpose digital I/O pin/Timer_A, compare: Out0 output/test mode select, input terminal for device programming and test
P1.6/TA1/TDI	19	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output/test data input terminal
P1.7/TA2/TDO/TDI [†]	20	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output/test data output terminal or data input during programming
P2.0/ACLK	8	I/O	General-purpose digital I/O pin/ACLK output
P2.1/INCLK	9	I/O	General-purpose digital I/O pin/Timer_A, clock signal at INCLK
P2.2/TA0	10	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI0B input, compare: Out0 output/BSL receive
P2.3/TA1	11	I/O	General-purpose digital I/O pin/Timer_A, capture: CCI1B input, compare: Out1 output
P2.4/TA2	12	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output
P2.5/ROSC	3	I/O	General-purpose digital I/O pin/Input for external resistor that defines the DCO nominal frequency
RST/NMI	7	Ι	Reset or nonmaskable interrupt input
TEST	1	Ι	Selects test mode for JTAG pins on Port1. Must be tied low with less than 30 k Ω .
V _{CC}	2		Supply voltage
V _{SS}	4		Ground reference
XIN	6	Ι	Input terminal of crystal oscillator
XOUT/TCLK	5	I/O	Output terminal of crystal oscillator or test clock input

[†] TDO or TDI is selected via JTAG instruction.



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short-form description

CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

instruction set

The instruction set consists of 51 instructions with three formats and seven address modes. Each instruction can operate on word and byte data. Table 1 shows examples of the three types of instruction formats; the address modes are listed in Table 2.

Program Counter	PC/R0
Stack Pointer	SP/R1
Status Register	SR/CG1/R2
Constant Generator	CG2/R3
General-Purpose Register	R4
General-Purpose Register	R5
General-Purpose Register	R6
General-Purpose Register	R7
General-Purpose Register	R8
General-Purpose Register	R9
General-Purpose Register	R10
General-Purpose Register	R11
General-Purpose Register	R12
General-Purpose Register	R13
General-Purpose Register	R14
General-Purpose Register	R15

Table 1. Instruction Word Formats

Dual operands, source-destination	e.g. ADD R4,R5	R4 + R5> R5
Single operands, destination only	e.g. CALL R8	PC>(TOS), R8> PC
Relative jump, un/conditional	e.g. JNE	Jump-on-equal bit = 0

ADDRESS MODE	S	D	SYNTAX	EXAMPLE	OPERATION
Register	•	•	MOV Rs,Rd	MOV R10,R11	R10> R11
Indexed	•	•	MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	M(2+R5)> M(6+R6)
Symbolic (PC relative)	•	•	MOV EDE,TONI		M(EDE)> M(TONI)
Absolute	•	•	MOV &MEM,&TCDAT		M(MEM)> M(TCDAT)
Indirect			MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10)> M(Tab+R6)
Indirect autoincrement	•		MOV @Rn+,Rm	MOV @R10+,R11	M(R10)> R11 R10 + 2> R10
Immediate	٠		MOV #X,TONI	MOV #45,TONI	#45> M(TONI)

Table 2. Address Mode Descriptions

NOTE: S = source D = destination



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operating modes

The MSP430 has one active mode and five software selectable low-power modes of operation. An interrupt event can wake up the device from any of the five low-power modes, service the request and restore back to the low-power mode on return from the interrupt program.

The following six operating modes can be configured by software:

- Active mode AM;
 - All clocks are active
- Low-power mode 0 (LPM0);
 - CPU is disabled ACLK and SMCLK remain active. MCLK is disabled
- Low-power mode 1 (LPM1);
 - CPU is disabled
 ACLK and SMCLK remain active. MCLK is disabled
 DCO's dc-generator is disabled if DCO not used in active mode
- Low-power mode 2 (LPM2);
 - CPU is disabled MCLK and SMCLK are disabled DCO's dc-generator remains enabled ACLK remains active
- Low-power mode 3 (LPM3);
 - CPU is disabled MCLK and SMCLK are disabled DCO's dc-generator is disabled ACLK remains active
- Low-power mode 4 (LPM4);
 - CPU is disabled ACLK is disabled MCLK and SMCLK are disabled DCO's dc-generator is disabled Crystal oscillator is stopped



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interrupt vector addresses

The interrupt vectors and the power-up starting address are located in the memory with an address range of 0FFFh-0FFE0h. The vector contains the 16-bit address of the appropriate interrupt handler instruction sequence.

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Power-up External reset Watchdog	WDTIFG (Note1) KEYV (Note 1)	Reset	0FFFEh	15, highest
NMI Oscillator fault Flash memory access violation	NMIIFG (Notes 1 and 5) OFIFG (Notes 1 and 5) ACCVIFG (Notes 1 and 5)	(non)-maskable, (non)-maskable, (non)-maskable	0FFFCh	14
			0FFFAh	13
			0FFF8h	12
			0FFF6h	11
Watchdog timer	WDTIFG	maskable	0FFF4h	10
Timer_A3	TACCR0 CCIFG (Note 2)	maskable	0FFF2h	9
Timer_A3	TACCR1 and TACCR2 CCIFGs, TAIFG (Notes 1 and 2)	maskable	0FFF0h	8
			0FFEEh	7
			0FFECh	6
			0FFEAh	5
			0FFE8h	4
I/O Port P2 (eight flags – see Note 3)	P2IFG.0 to P2IFG.7 (Notes 1 and 2)	maskable	0FFE6h	3
I/O Port P1 (eight flags)	P1IFG.0 to P1IFG.7 (Notes 1 and 2)	maskable	0FFE4h	2
			0FFE2h	1
			0FFE0h	0, lowest

NOTES: 1. Multiple source flags

2. Interrupt flags are located in the module

3. There are eight Port P2 interrupt flags, but only six Port P2 I/O pins (P2.0-5) are implemented on the '11x devices.

4. Nonmaskable: neither the individual nor the general interrupt enable bit will disable an interrupt event.

5. (non)-maskable: the individual interrupt enable bit can disable an interrupt event, but the general interrupt enable cannot.

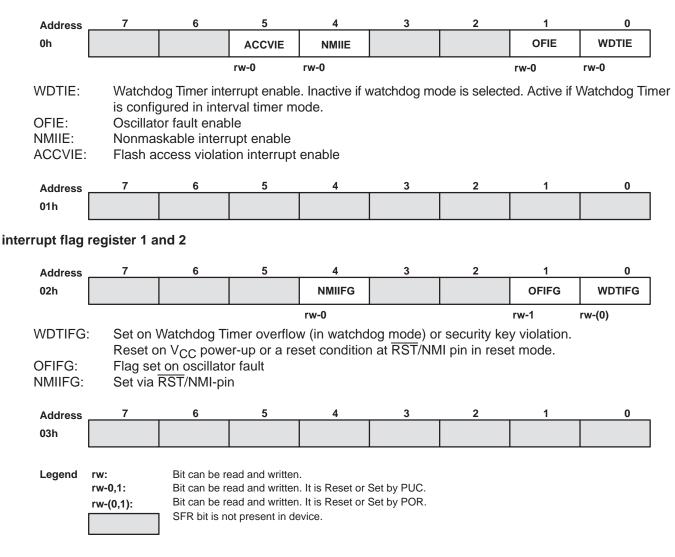


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special function registers

Most interrupt and module enable bits are collected into the lowest address space. Special function register bits that are not allocated to a functional purpose are not physically present in the device. Simple software access is provided with this arrangement.

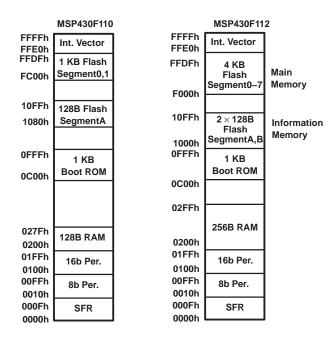
interrupt enable 1 and 2





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memory organization



bootstrap loader (BSL)

The MSP430 bootstrap loader (BSL) enables users to program the flash memory or RAM using a UART serial interface. Access to the MSP430 memory via the BSL is protected by user-defined password. For complete description of the features of the BSL and its implementation, see the Application report *Features of the MSP430 Bootstrap Loader*, Literature Number SLAA089.

BSL Function	DW & PW Package Pins
Data Transmit	14 - P1.1
Data Receive	10 - P2.2

flash memory

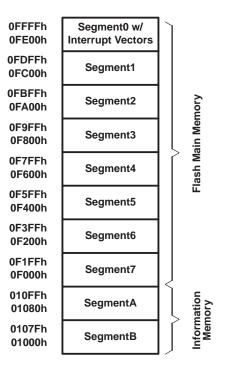
The flash memory can be programmed via the JTAG port, the bootstrap loader, or in-system by the CPU. The CPU can perform single-byte and single-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and two segments of information memory (A and B) of 128 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A and B can be erased individually, or as a group with segments 0–n. Segments A and B are also called *information memory*.
- New devices may have some bytes programmed in the information memory (needed for test during manufacturing). The user should perform an erase of the information memory prior to the first use.



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flash memory (continued)



NOTE: All segments not implemented on all devices.

peripherals

Peripherals are connected to the CPU through data, address, and control busses and can be handled using all instructions. For complete module descriptions, refer to the *MSP430x1xx Family User's Guide*, literature number SLAU049.

oscillator and system clock

The clock system is supported by the basic clock module that includes support for a 32768-Hz watch crystal oscillator, an internal digitally-controlled oscillator (DCO) and a high frequency crystal oscillator. The basic clock module is designed to meet the requirements of both low system cost and low-power consumption. The internal DCO provides a fast turn-on clock source and stabilizes in less than 6 μ s. The basic clock module provides the following clock signals:

- Auxiliary clock (ACLK), sourced from a 32768-Hz watch crystal or a high frequency crystal.
- Main clock (MCLK), the system clock used by the CPU.
- Sub-Main clock (SMCLK), the sub-system clock used by the peripheral modules.



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digital I/O

There are two 8-bit I/O ports implemented—ports P1 and P2 (only six P2 I/O signals are available on external pins):

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Edge-selectable interrupt input capability for all the eight bits of port P1 and six bits of port P2.
- Read/write access to port-control registers is supported by all instructions.

NOTE:

Six bits of port P2, P2.0 to P2.5, are available on external pins – but all control and data bits for port P2 are implemented.

watchdog timer

The primary function of the watchdog timer (WDT) module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be configured as an interval timer and can generate interrupts at selected time intervals.

timer_A3

Timer_A3 is a 16-bit timer/counter with three capture/compare registers. Timer_A3 can support multiple capture/compares, PWM outputs, and interval timing. Timer_A3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

		Timer_A3 Sig	nal Connections		
Input Pin Number	Device Input Signal	Module Input Name	Module Block	Module Output Signal	Output Pin Number
13 - P1.0	TACLK	TACLK			
	ACLK	ACLK			
	SMCLK	SMCLK	Timer	NA	
9 - P2.1	INCLK	INCLK			
14 - P1.1	TA0	CCI0A			14 - P1.1
10 - P2.2	TA0	CCI0B	0050	TAO	18 - P1.5
	DVSS	GND	CCR0		10 - P2.2
	DVCC	VCC	1		
15 - P1.2	TA1	CCI1A			15 - P1.2
11 - P2.3	TA1	CCI1B	0054	T 4 4	19 - P1.6
	DVSS	GND	CCR1 TA1		11 - P2.3
	DV _{CC}	V _{CC}			
16 - P1.3	TA2	CCI2A			16 - P1.3
	ACLK (internal)	CCI2B	0000	TA2	20 - P1.7
	DVSS	GND	CCR2		12 - P2.4
	DVCC	VCC			



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peripheral file map

P	ERIPHERALS WITH WORD ACCE	SS	
Timer_A	Reserved Reserved Reserved Capture/compare register Capture/compare register Capture/compare register Timer_A register Reserved Reserved Reserved Reserved Capture/compare control Capture/compare control Capture/compare control Timer_A control Timer_A interrupt vector	TACCR2 TACCR1 TACCR0 TAR TACCTL2 TACCTL1 TACCTL0 TACTL TAIV	017Eh 017Ch 017Ah 017Ah 0178h 0176h 0172h 0172h 0172h 016Ch 016Ch 016Ch 016Ah 0166h 0166h 0162h 0162h 0162h
Flash Memory	Flash control 3	FCTL3	012Ch
	Flash control 2	FCTL2	012Ah
	Flash control 1	FCTL1	0128h
Watchdog	Watchdog/timer control	WDTCTL	0120h
Ρ	ERIPHERALS WITH BYTE ACCES	SS	
Basic Clock	Basic clock sys. control2	BCSCTL2	058h
	Basic clock sys. control1	BCSCTL1	057h
	DCO clock freq. control	DCOCTL	056h
Port P2	Port P2 selection	P2SEL	02Eh
	Port P2 interrupt enable	P2IE	02Dh
	Port P2 interrupt edge select	P2IES	02Ch
	Port P2 interrupt flag	P2IFG	02Bh
	Port P2 direction	P2DIR	02Ah
	Port P2 output	P2OUT	029h
	Port P2 input	P2IN	029h
Port P1	Port P1 selection	P1SEL	026h
	Port P1 interrupt enable	P1IE	025h
	Port P1 interrupt edge select	P1IES	024h
	Port P1 interrupt flag	P1IFG	023h
	Port P1 direction	P1DIR	022h
	Port P1 output	P1OUT	021h
	Port P1 input	P1IN	020h
Special Function	SFR interrupt flag2	IFG2	003h
	SFR interrupt flag1	IFG1	002h
	SFR interrupt enable2	IE2	001h
	SFR interrupt enable1	IE1	000h



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absolute maximum ratings[†]

Voltage applied at V _{CC} to V _{SS}	
Voltage applied to any pin (referenced to V _{SS})	\dots –0.3 V to V _{CC} +0.3 V
Diode current at any device terminal	±2 mA
Storage temperature, T _{sta} (unprogrammed device)	–55°C to 150°C
Storage temperature, T _{stg} (programmed device)	−40°C to 85°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE: All voltages referenced to V_{SS} .

recommended operating conditions

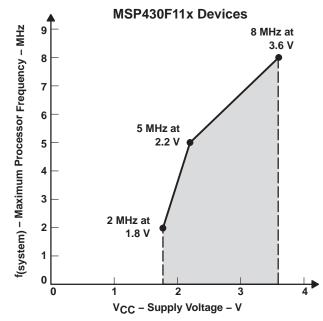
			MIN	NOM	MAX	UNITS
Supply voltage during program execution, V _{CC} (see Note 1)		1.8		3.6	V	
Supply voltage during program/erase flash memory, V _{CC}			2.7		3.6	V
Supply voltage, V _{SS}				0		V
Operating free-air temperature range, T _A		-40		85	°C	
	LF mode selected, XTS=0	Watch crystal		32768		Hz
LFXT1 crystal frequency, f(LFXT1) (see Note 2)		Ceramic resonator	450		8000	
	XT1 mode selected, XTS=1	Crystal	1000		8000	kHz
Processor frequency f _(system) (MCLK signal)		V _{CC} = 1.8 V	dc		2	MHz
		V _{CC} = 2.2 V	dc		5	MHz
			dc		8	MHz

NOTES: 1. The LFXT1 oscillator in LF-mode requires a resistor of 5.1 M Ω from XOUT to V_{SS} when V_{CC} <2.5 V.

The LFXT1 oscillator in XT1-mode accepts a ceramic resonator or a crystal frequency of 4 MHz at $V_{CC} \ge 2.2 V$.

The LFXT1 oscillator in XT1-mode accepts a ceramic resonator or a crystal frequency of 8 MHz at $V_{CC} \ge 2.8$ V.

2. The LFXT1 oscillator in LF-mode requires a watch crystal. The LFXT1 oscillator in XT1-mode accepts a ceramic resonator or crystal.



NOTE: Minimum processor frequency is defined by system clock. Flash program or erase operations require a minimum V_{CC} of 2.7 V.





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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
		$T_{A} = -40^{\circ}C + 85^{\circ}C,$			200	250	μA
I(AM) Active mode	Active mode	f(MCLK) = f(SMCLK) = 1 MHz, f(ACLK) = 32,768 Hz	$V_{CC} = 3 V$		300	350	μΛ
		$T_{A} = -40^{\circ}C + 85^{\circ}C,$	$V_{CC} = 2.2 V$		1.6	3	μA
		f(MCLK) = f(SMCLK) = f(ACLK) = 4096 Hz	$V_{CC} = 3 V$		3	4.3	μA
I(CPLIOff) Low-power mode, (LPM0)	$T_A = -40^{\circ}C + 85^{\circ}C,$	$V_{CC} = 2.2 V$		32	45		
I(CPUOff)		0) $f(MCLK) = 0, f(SMCLK) = 1 MHz, f(ACLK) = 32,768 Hz$	$V_{CC} = 3 V$		55	70	μA
I(LPM2) Low-power mode, (LPM2)		$T_A = -40^{\circ}C + 85^{\circ}C$,	$V_{CC} = 2.2 V$		11	14	μA
	Low-power mode, (LPMZ)	f(MCLK) = f(SMCLK) = 0 MHz, f(ACLK) = 32,768 Hz, SCG0 = 0	V _{CC} = 3 V		17	22	
		$T_{A} = -40^{\circ}C$			0.8	1.2	μΑ μΑ
		$T_A = 25^{\circ}C$	V _{CC} = 2.2 V		0.7	1	
10	Low-power mode, (LPM3)	$T_A = 85^{\circ}C$			1.6	2.3	
I(LPM3)	Low-power mode, (LFING)	$T_A = -40^{\circ}C$			1.8	2.2	
		$T_A = 25^{\circ}C$	$V_{CC} = 3 V$		1.6	1.9	
		$T_A = 85^{\circ}C$			2.3	3.4	
		$T_A = -40^{\circ}C$ $f_{(MCLK)} = 0 \text{ MHz}$			0.1	0.5	
l(LPM4)	Low-power mode, (LPM4)	$T_A = 25^{\circ}C$ f(smc(k) = 0 MHz.	V _{CC} = 2.2 V/3 V		0.1	0.5	μA
		$T_A = 85^{\circ}C$ f(ACLK) = 0 Hz, SCG0 = 1			0.8	1.9	

supply current (into V_{CC}) excluding external current

NOTE: All inputs are tied to 0 V or V_{CC}. Outputs do not source or sink any current.

current consumption of active mode versus system frequency, F version

 $I_{AM} = I_{AM[1 \text{ MHz}]} \times f_{system} [MHz]$

current consumption of active mode versus supply voltage, F version

 $I_{AM} = I_{AM[3 V]} + 120 \mu A/V \times (V_{CC} - 3 V)$



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

Schmitt-trigger inputs Port 1 to Port P2; P1.0 to P1.7, P2.0 to P2.5

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
V	Depitive point insut thread and units as	$V_{CC} = 2.2 V$	1.1	1.3	V
V _{IT+}	Positive-going input threshold voltage	$V_{CC} = 3 V$	1.5	5 1.8	V
N/		$V_{CC} = 2.2 V$	V _{CC} = 2.2 V 0.4	0.9	v
VIT-	Negative-going input threshold voltage	$V_{CC} = 3 V$.90	1.2	
. v.	Input voltage bystoresis (V/)/)	$V_{CC} = 2.2 V$	0.3	1	V
V _{hys}	Input voltage hysteresis, (V _{IT+} – V _{IT} –)	$V_{CC} = 3 V$	0.5	1.4	v

standard inputs – RST/NMI; TCK, TMS, TDI

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
VIL	Low-level input voltage	$V_{CC} = 2.2 V / 3 V$	VSS	V _{SS} +0.6	V
V_{IH}	High-level input voltage		0.8×V _{CC}	V _{CC}	V

inputs Px.x, TAx

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
			2.2 V/3 V	1.5			cycle
^t (int)	External interrupt timing	Port P1, P2: P1.x to P2.x, External trigger signal for the interrupt flag, (see Note 1)	2.2 V	62			
. ,			3 V	50			ns
	Timer_A, capture timing	TA0, TA1, TA2 (see Note 2)	2.2 V/3 V	1.5			cycle
^t (cap)			2.2 V	62			ns
× 17			3 V	50			
(Timer_A clock frequency		2.2 V			8	N411-
f(TAext)	externally applied to pin	TACLK, INCLK $t(H) = t(L)$	3 V			10	MHz
	Trees Asland for more as		2.2 V			8	N 41 1-
^f (TAint)	Timer_A clock frequency	SMCLK or ACLK signal selected	3 V			10	MHz

NOTES: 1. The external signal sets the interrupt flag every time the minimum t_(int) cycle and time parameters are met. It may be set even with trigger signals shorter than t_(int). Both the cycle and timing specifications must be met to ensure the flag is set. t_(int) is measured in MCLK cycles.

The external capture signal triggers the capture event every time the mimimum t_(Cap) cycle and time parameters are met. A capture may be triggered with capture signals even shorter than t_(Cap). Both the cycle and timing specifications must be met to ensure a correct capture of the 16-bit timer value and to ensure the flag is set.

leakage current

PARAMETER TEST CONDITIONS		ITIONS	MIN	TYP	MAX	UNIT	
llkg(Px.x)	19ab Secondaria Instance and	Port P1: P1.x, $0 \le x \le 7$ (see Notes 1 and 2)	$V_{CC} = 2.2 \text{ V/3 V},$			±50	
	High-impedance leakage current	Port P2: P2.x, $0 \le x \le 5$ (see Notes 1 and 2)	$V_{CC} = 2.2 \text{ V/3 V},$			±50	nA

NOTES: 1. The leakage current is measured with VSS or VCC applied to the corresponding pin(s), unless otherwise noted.

2. The leakage of the digital port pins is measured individually. The port pin must be selected for input and there must be no optional pullup or pulldown resistor.



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS		MIN	TYP MAX	UNIT
		$I_{(OHmax)} = -1.5 \text{ mA}$		See Note 1	V _{CC} -0.25	VCC	
	High-level output voltage	I _(OHmax) = -6 mA	V _{CC} = 2.2 V	See Note 2	V _{CC} -0.6	VCC	V
Vон	Port 1	$I_{(OHmax)} = -1.5 \text{ mA}$	$V_{CC} = 3V$	See Note 1	V _{CC} -0.25	VCC	v
		I _(OHmax) = -6 mA		See Note 2	V _{CC} -0.6	VCC	
		$I_{(OHmax)} = -1 \text{ mA}$	V _{CC} = 2.2 V	See Note 3	V _{CC} -0.25	V _{CC}	
	High-level output voltage	$I_{(OHmax)} = -3.4 \text{ mA}$		See Note 3	V _{CC} -0.6	V _{CC}	V
Vон	Port 2	$I_{(OHmax)} = -1 \text{ mA}$		See Note 3	V _{CC} -0.25	V _{CC}	
		$I_{(OHmax)} = -3.4 \text{ mA}$	VCC = 3 V	See Note 3	V _{CC} -0.6	VCC	
		I _(OLmax) = 1.5 mA		See Note 1	VSS	V _{SS} +0.25	
	Low-level output voltage	$I_{(OLmax)} = 6 \text{ mA}$	V _{CC} = 2.2 V	See Note 2	VSS	V _{SS} +0.6	V
VOL	Port 1 and Port 2	$I_{(OLmax)} = 1.5 \text{ mA}$		See Note 1	V _{SS}	V _{SS} +0.25	v
		I _(OLmax) = 6 mA	VCC = 3 V	See Note 2	V _{SS}	V _{SS} +0.6	

outputs Port 1 to Port 2; P1.0 to P1.7, P2.0 to P2.5

NOTES: 1. The maximum total current, I_{OHmax} and I_{OLmax}, for all outputs combined, should not exceed ±12 mA to hold the maximum voltage drop specified.

 The maximum total current, I_{OHmax} and I_{OLmax}, for all outputs combined, should not exceed ±48 mA to hold the maximum voltage drop specified.

3. One output loaded at a time.

outputs P1.x, P2.x, TAx

	PARAMETER	TEST CO	NDITIONS	V _{CC}	MIN	TYP	MAX	UNIT	
^f (P20)		P2.0/ACLK, C _L = 20 pF		2.2 V/3 V			^f System		
^f (TAx)	Output frequency	TA0, TA1, TA2, $C_L = 20 \text{ pF}$ Internal clock source, SMCI (See Note 1)	nternal clock source, SMCLK signal applied See Note 1)				fSystem	MHz	
			fSMCLK = fLFXT1 = fXT1	2.2 V/3 V	40%		60%		
		P1.4/SMCLK, C _L = 20 pF	fSMCLK = fLFXT1 = fLF		35%		65%		
			fSMCLK = fLFXT1/n		50%– 15 ns	50%	50%+ 15 ns		
^t (Xdc)	Duty cycle of O/P frequency		fSMCLK = fDCOCLK	2.2 V/3 V	50%– 15 ns	50%	50%+ 15 ns		
			$f_{P20} = f_{LFXT1} = f_{XT1}$		40%		60%		
		P2.0/ACLK, C _L = 20 pF	$f_{P20} = f_{LFXT1} = f_{LF}$	2.2 V/3 V	30%		70%		
		$f_{P20} = f_{LFXT1/n}$				50%			
t(TAdc)		TA0, TA1, TA2, C _L = 20 pF,	Duty cycle = 50%	2.2 V/3 V		0	±50	ns	

NOTE 1: The limits of the system clock MCLK have to be met. MCLK and SMCLK can have different frequencies.



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

PUC/POR

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
^t (POR_Delay)			_		150	250	μs
		$T_A = -40^{\circ}C$		1.4		1.8	V
VPOR	POR	$T_A = 25^{\circ}C$	$1/2 = -2.2 \frac{1}{2}$	1.1		1.5	V
		$T_A = 85^{\circ}C$	$V_{CC} = 2.2 \text{ V/3 V}$	0.8		1.2	V
V _(min)				0		0.4	V
t(reset)	PUC/POR	Reset is accepted internally		2			μs

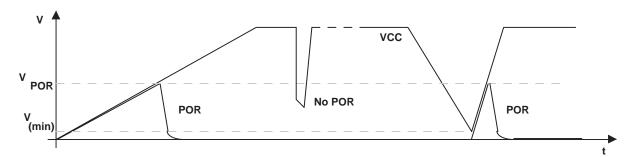


Figure 2. Power-On Reset (POR) vs Supply Voltage

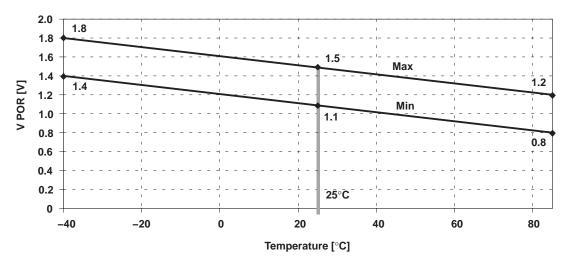


Figure 3. V_{POR} vs Temperature



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
^t (LPM0)		$V_{CC} = 2.2 V/3 V$		100			
t(LPM2)		V _{CC} = 2.2 V/3 V		100		ns	
		f _(MCLK) = 1 MHz, V _{CC} = 2.2 V/3 V			6		
^t (LPM3)		$f_{(MCLK)} = 2 \text{ MHz}, V_{CC} = 2.2 \text{ V/3 V}$			6	β μs	
	Delay time (see Note 1)	$f_{(MCLK)} = 3 \text{ MHz}, V_{CC} = 2.2 \text{ V/3 V}$			6		
		f _(MCLK) = 1 MHz, V _{CC} = 2.2 V/3 V			6		
^t (LPM4)		$f_{(MCLK)} = 2 \text{ MHz}, V_{CC} = 2.2 \text{ V/3 V}$			6	μs	
. ,		f(MCLK) = 3 MHz, V _{CC} = 2.2 V/3 V			6		

wake-up from lower power modes (LPMx)

NOTE 1: Parameter applicable only if DCOCLK is used for MCLK.

RAM

	PARAMETER	MIN	TYP	MAX	UNIT
V(RAMh)	CPU halted (see Note 1)	1.6			V

NOTE 1: This parameter defines the minimum supply voltage V_{CC} when the data in the program memory RAM remains unchanged. No program execution should happen during this supply voltage condition.



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
		V _{CC} = 2.2 V	0.08	0.12	0.15	
f(DCO03)	$R_{sel} = 0$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 3 V	0.08	0.13	0.16	MHz
1		V _{CC} = 2.2 V	0.14	0.19	0.23	MHz
f(DCO13)	$R_{sel} = 1$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	$V_{CC} = 3 V$	0.14	0.18	0.22	IVIHZ
fraccos	$R_{sel} = 2$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	$V_{CC} = 2.2 V$	0.22	0.30	0.36	MHz
f(DCO23)	$N_{Sel} = 2, DCC = 3, MOD = 0, DCCR = 0, NA = 23 C$	$V_{CC} = 3 V$	0.22	0.28	0.34	
frages	$R_{sel} = 3$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 2.2 V	0.37	0.49	0.59	MHz
f(DCO33)	$R_{Sel} = 3, DCO = 3, MOD = 0, DCOR = 0, TA = 23 C$	$V_{CC} = 3 V$	0.37	0.47	0.56	IVILL
financia	$R_{sel} = 4$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 2.2 V	0.61	0.77	0.93	MHz
f(DCO43)	$R_{Sel} = 4$, $DCO = 3$, $MOD = 0$, $DCOR = 0$, $TA = 23 C$	V _{CC} = 3 V	0.61	0.75	0.9	IVILL
4		V _{CC} = 2.2 V	1	1.2	1.5	MHz
f(DCO53)	$R_{sel} = 5$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 3 V	1	1.3	1.5	
4	O63) $R_{sel} = 6$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 2.2 V	1.6	1.9	2.2	MHz
f(DCO63)		$V_{CC} = 3 V$	1.69	2.0	2.29	IVITZ
<i>t</i>		V _{CC} = 2.2 V	2.4	2.9	3.4	MHz
f(DCO73)	$R_{sel} = 7$, DCO = 3, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	$V_{CC} = 3 V$	2.7	3.2	3.65	IVITIZ
		V _{CC} = 2.2 V	4	4.5	4.9	
f(DCO77)	$R_{sel} = 7$, DCO = 7, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 3 V	4.4	4.9	5.4	MHz
f(DCO47)	$R_{sel} = 4$, DCO = 7, MOD = 0, DCOR = 0, $T_A = 25^{\circ}C$	V _{CC} = 2.2 V/3 V	FDCO40 x1.7	FDCO40 x2.1	FDCO40 x2.5	MHz
S _(Rsel)	S _R = f _{Rsel+1} /f _{Rsel}	V _{CC} = 2.2 V/3 V	1.35	1.65	2	
S(DCO)	S _{DCO} = f _{DCO+1} /f _{DCO}	V _{CC} = 2.2 V/3 V	1.07	1.12	1.16	ratio
_	Temperature drift, $R_{sel} = 4$, DCO = 3, MOD = 0	V _{CC} = 2.2 V	-0.31	-0.36	-0.40	a. 10 C
Dt	(see Note 1)	V _{CC} = 3 V	-0.33	-0.38	-0.43	%/°C
DV	Drift with V _{CC} variation, $R_{Sel} = 4$, DCO = 3, MOD = 0 (see Note 1)	V _{CC} = 2.2 V/3 V	0	5	10	%/V

NOTE 1: These parameters are not production tested.

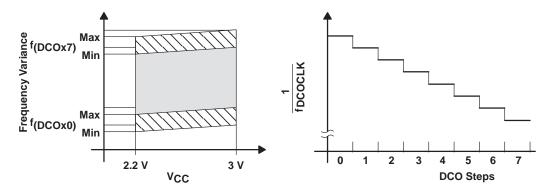


Figure 4. DCO Characteristics



electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

main DCO characteristics

- Individual devices have a minimum and maximum operation frequency. The specified parameters for f_(DCOx0) to f_(DCOx7) are valid for all devices.
- All ranges selected by Rsel(n) overlap with Rsel(n+1): Rsel0 overlaps Rsel1, ... Rsel6 overlaps Rsel7.
- DCO control bits DCO0, DCO1, and DCO2 have a step size as defined by parameter S_{DCO}.
- Modulation control bits MOD0 to MOD4 select how often f_(DCO+1) is used within the period of 32 DCOCLK cycles. The frequency f_(DCO) is used for the remaining cycles. The frequency is an average equal to:

$$f_{average} = \frac{32 \times f_{(DCO)} \times f_{(DCO+1)}}{MOD \times f_{(DCO)} + (32 - MOD) \times f_{(DCO+1)}}$$

crystal oscillator, LFXT1

	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
0	hand an a firm a	XTS=0; LF mode selected. $V_{CC} = 2.2 V / 3 V$	12	
C _{XIN} Input capacita	Input capacitance	XTS=1; XT1 mode selected. $V_{CC} = 2.2 V / 3 V$ (Note 1)	2	pF
CXOUT Output capacitance	Quitaut anna itanaa	XTS=0; LF mode selected. $V_{CC} = 2.2 V / 3 V$	12	-5
	XTS=1; XT1 mode selected. $V_{CC} = 2.2 V / 3 V$ (Note 1)	2	pF	
VIL	Input levels at XIN	V _{CC} = 2.2 V/3 V (see Note 2)	V _{SS} 0.2×V _{CC}	V
VIH			0.8×VCC VCC	v

NOTES: 1. The oscillator needs capacitors at both terminals, with values specified by the crystal manufacturer.

2. Applies only when using an external logic-level clock source. Not applicable when using a crystal or resonator.



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electrical characteristics over recommended operating free-air temperature (unless otherwise noted) (continued)

Flash Memory

	PARAMETER	TEST CONDITIONS	Vcc	MIN	NOM	MAX	UNIT
V _{CC} (PGM/ ERASE)	Program and Erase supply voltage			2.7		3.6	V
^f FTG	Flash Timing Generator frequency			257		476	kHz
IPGM	Supply current from DV _{CC} during program		2.7 V/ 3.6 V		3	5	mA
IERASE	Supply current from DV _{CC} during erase		2.7 V/ 3.6 V		3	5	mA
^t CPT	Cumulative program time	see Note 1	2.7 V/ 3.6 V			4	ms
^t CMErase	Cumulative mass erase time	see Note 2	2.7 V/ 3.6 V	200			ms
	Program/Erase endurance			10 ⁴	105		cycles
^t Retention	Data retention duration	$T_J = 25^{\circ}C$		100			years
^t Word	Word or byte program time				35		
^t Block, 0	Block program time for 1 st byte or word	1			30		
^t Block, 1-63	Block program time for each additional byte or word				21		
^t Block, End	Block program end-sequence wait time	see Note 3			6		^t FTG
t _{Mass} Erase	Mass erase time]			5297		
tSeg Erase	Segment erase time				4819		

NOTES: 1. The cumulative program time must not be exceeded when writing to a 64-byte flash block. This parameter applies to all programming methods: individual word/byte write and block write modes.

 The mass erase duration generated by the flash timing generator is at least 11.1ms (= 5297x1/fFTG,max = 5297x1/476kHz). To achieve the required cumulative mass erase time the Flash Controller's mass erase operation can be repeated until this time is met. (A worst case minimum of 19 cycles are required).

3. These values are hardwired into the Flash Controller's state machine ($t_{FTG} = 1/f_{FTG}$).

JTAG Interface

	PARAMETER	TEST CONDITIONS	v _{cc}	MIN	NOM	МАХ	UNIT
4	TOK	ana Nata 4	2.2 V	0		5	MHz
TCK	TCK input frequency	see Note 1	3 V	0		10	MHz
RInternal	Internal pull-up resistance on TMS, TCK, TDI/TCLK	see Note 2	2.2 V/ 3 V	25	60	90	kΩ

NOTES: 1. f_{TCK} may be restricted to meet the timing requirements of the module selected.

2. TMS, TDI/TCLK, and TCK pull-up resistors are implemented in all versions.

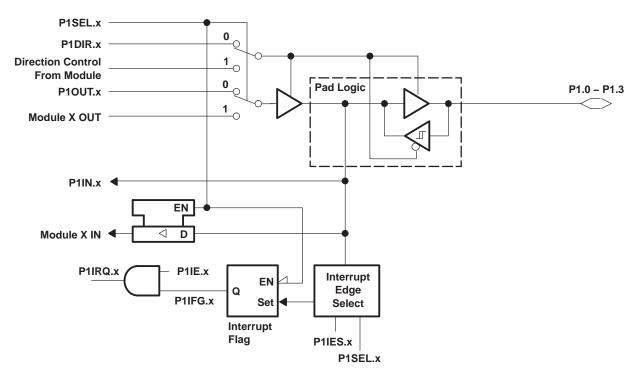


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APPLICATION INFORMATION

input/output schematic





NOTE:	x = Bit/identifier,	0 to 3 for port P1
-------	---------------------	--------------------

PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P1Sel.0	P1DIR.0	P1DIR.0	P1OUT.0	V _{SS}	P1IN.0	TACLK [†]	P1IE.0	P1IFG.0	P1IES.0
P1Sel.1	P1DIR.1	P1DIR.1	P1OUT.1	Out0 signal†	P1IN.1	CCI0A [†]	P1IE.1	P1IFG.1	P1IES.1
P1Sel.2	P1DIR.2	P1DIR.2	P1OUT.2	Out1 signal [†]	P1IN.2	CCI1A [†]	P1IE.2	P1IFG.2	P1IES.2
P1Sel.3	P1DIR.3	P1DIR.3	P1OUT.3	Out2 signal†	P1IN.3	CCI2A [†]	P1IE.3	P1IFG.3	P1IES.3

[†]Signal from or to Timer_A

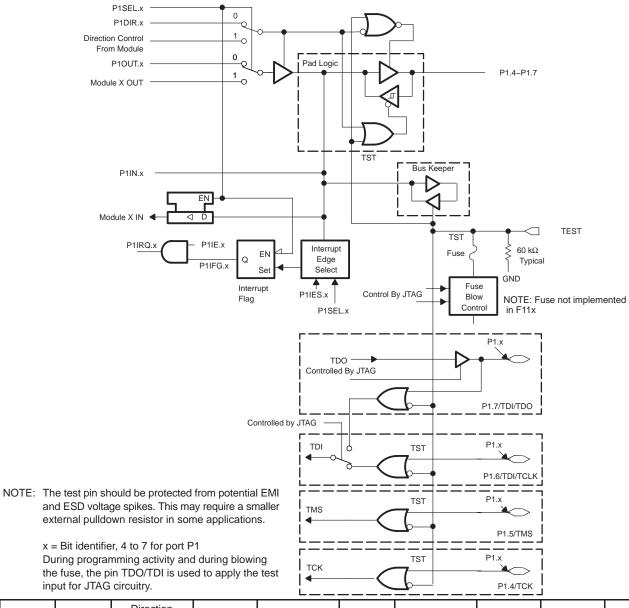


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APPLICATION INFORMATION

input/output schematic (continued)

Port P1, P1.4 to P1.7, input/output with Schmitt-trigger and in-system access features



PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P1Sel.4	P1DIR.4	P1DIR.4	P1OUT.4	SMCLK	P1IN.4	unused	P1IE.4	P1IFG.4	P1IES.4
P1Sel.5	P1DIR.5	P1DIR.5	P1OUT.5	Out0 signal [†]	P1IN.5	unused	P1IE.5	P1IFG.5	P1IES.5
P1Sel.6	P1DIR.6	P1DIR.6	P1OUT.6	Out1 signal [†]	P1IN.6	unused	P1IE.6	P1IFG.6	P1IES.6
P1Sel.7	P1DIR.7	P1DIR.7	P1OUT.7	Out2 signal [†]	P1IN.7	unused	P1IE.7	P1IFG.7	P1IES.7

[†]Signal from or to Timer_A

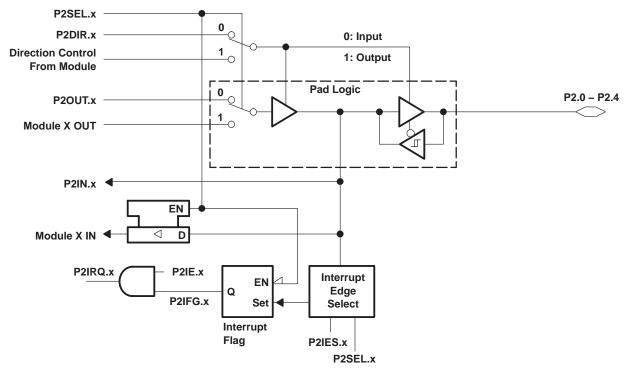


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APPLICATION INFORMATION

input/output schematic (continued)





NOTE: x = Bit Identifier, 0 to 4 For Port P2

PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.0	P2DIR.0	P2DIR.0	P2OUT.0	ACLK	P2IN.0	unused	P2IE.0	P2IFG.0	P1IES.0
P2Sel.1	P2DIR.1	P2DIR.1	P2OUT.1	VSS	P2IN.1	INCLK [†]	P2IE.1	P2IFG.1	P1IES.1
P2Sel.2	P2DIR.2	P2DIR.2	P2OUT.2	Out0 signal [†]	P2IN.2	CCI0B [†]	P2IE.2	P2IFG.2	P1IES.2
P2Sel.3	P2DIR.3	P2DIR.3	P2OUT.3	Out1 signal [†]	P2IN.3	CCI1B [†]	P2IE.3	P2IFG.3	P1IES.3
P2Sel.4	P2DIR.4	P2DIR.4	P2OUT.4	Out2 signal [†]	P2IN.4	unused	P2IE.4	P2IFG.4	P1IES.4

[†]Signal from or to Timer_A

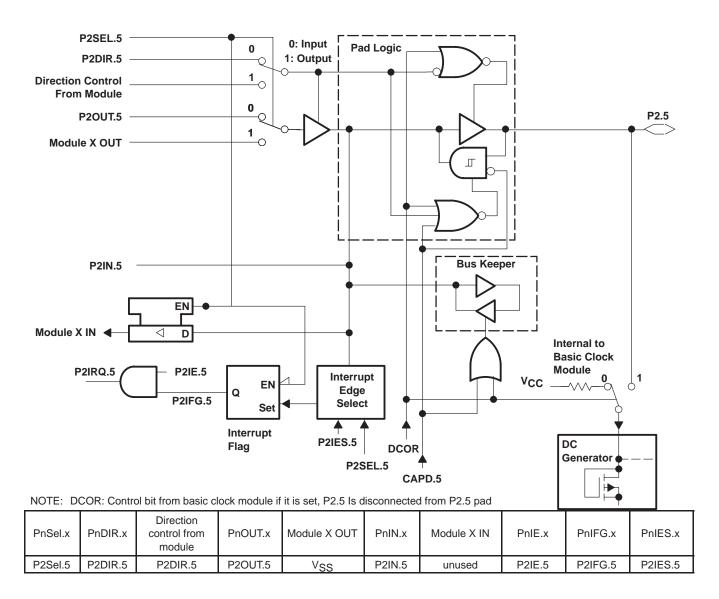


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APPLICATION INFORMATION

input/output schematic (continued)

Port P2, P2.5, input/output with Schmitt-trigger and ROSC function for the Basic Clock module

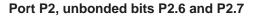


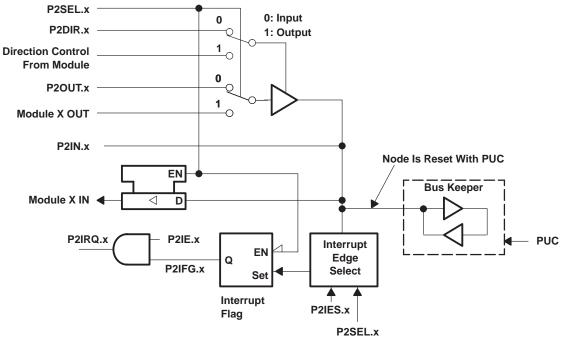


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APPLICATION INFORMATION

input/output schematic (continued)





NOTE: x = Bit/identifier, 6 to 7 for port P2 without external pins

P2Sel.x	P2DIR.x	Direction control from module	P2OUT.x	Module X OUT	P2IN.x	Module X IN	P2IE.x	P2IFG.x	P2IES.x
P2Sel.6	P2DIR.6	P2DIR.6	P2OUT.6	VSS	P2IN.6	unused	P2IE.6	P2IFG.6	P2IES.6
P2Sel.7	P2DIR.7	P2DIR.7	P2OUT.7	VSS	P2IN.7	unused	P2IE.7	P2IFG.7	P2IES.7

NOTE: A good use of the unbonded bits 6 and 7 of port P2 is to use the interrupt flags. The interrupt flags can not be influenced from any signal other than from software. They work then as a soft interrupt.



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APPLICATION INFORMATION

JTAG fuse check mode

The JTAG protection fuse is not implemented in the MSP430F11x devices.





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430F112IPW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	430F112	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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